

Lecture 6: Electromagnetic Power

Outline

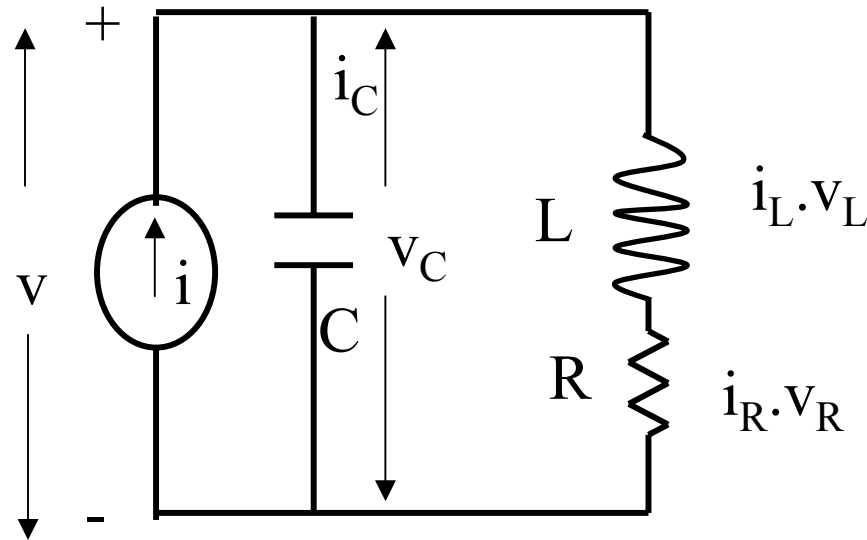
1. Power and energy in a circuit
2. Power and energy density in a distributed system
3. Surface Impedance

September 23, 2003



Power in a Circuit

Power: $vi = v_C i_C + v_L i_L + v_R i_R$



Constitutive relations
for the resistor

$$v_R = i_R R,$$

the inductor

$$v_L = L \frac{d}{dt} i_L,$$

and the capacitor

$$i_C = C \frac{d}{dt} v_C,$$

$$vi = \frac{d}{dt} \underbrace{\left(\frac{1}{2} C v_C^2 \right)}_{W_e} + \frac{d}{dt} \underbrace{\left(\frac{1}{2} L i_L^2 \right)}_{W_m} + R i_R^2$$

Energy

W_e

W_m



Average Power for a Sinusoidal Drive

The time average power is

$$\langle vi \rangle \equiv \frac{1}{T} \int_0^T vi \, dt$$

Power is a bilinear term, not a linear one, so must use real variables,

$$C(t) = \frac{1}{2} (\hat{C} e^{j\omega t} + \hat{C}^* e^{-j\omega t})$$

The time average power is then

$$\langle vi \rangle = \frac{1}{4T} \int_0^T (\hat{v}\hat{i}^* + (\hat{v}\hat{i}^*)^* + \hat{v}\hat{i} e^{j2\omega t} + (\hat{v}\hat{i})^* e^{-j2\omega t}) \, dt$$

which gives

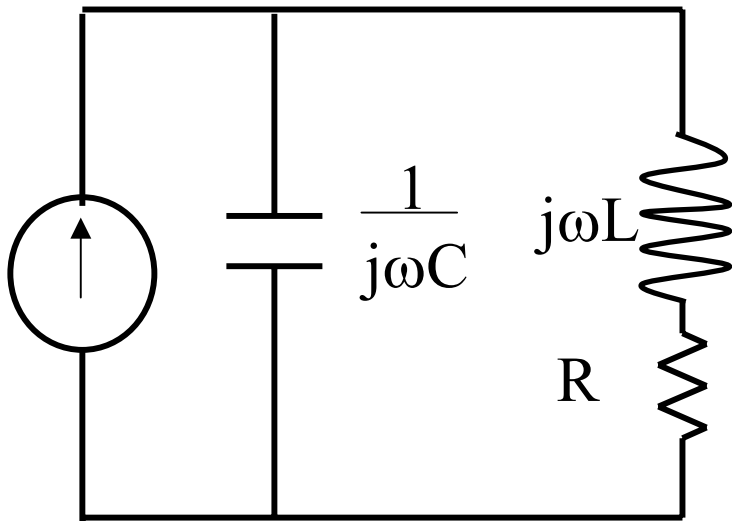
$$\langle vi \rangle = \frac{1}{2} \operatorname{Re} \{ \hat{v}\hat{i}^* \}$$



Average Power for a Sinusoidal Drive

$$\langle vi \rangle = \frac{1}{2} \operatorname{Re} \{ \hat{v} \hat{i}^* \}$$

$$\langle vi \rangle = \frac{|\hat{i}|^2}{2} \operatorname{Re} \{ Z(\omega) \} = \frac{|\hat{v}|^2}{2} \operatorname{Re} \left\{ \frac{1}{Z(\omega)} \right\}$$



$$Z(\omega) = j\omega C + \frac{1}{R + j\omega L}$$

$$\langle vi \rangle = \frac{|\hat{v}|^2}{2} \operatorname{Re} \left\{ \frac{R}{R^2 + \omega^2 L^2} \right\}$$



Power in Distributed Systems

Use the full Maxwell's Equations,

$$\begin{aligned} \mathbf{E} \cdot \left\{ \nabla \times \mathbf{H} = \frac{\partial \mathbf{D}}{\partial t} + \mathbf{J} \right\} \\ \text{--- } \mathbf{H} \cdot \left\{ \nabla \times \mathbf{E} = -\frac{\partial \mathbf{B}}{\partial t} \right\} \end{aligned}$$

$$-\nabla \cdot (\mathbf{E} \times \mathbf{H}) = \mathbf{E} \cdot \frac{\partial \mathbf{D}}{\partial t} + \mathbf{H} \cdot \frac{\partial \mathbf{B}}{\partial t} + \mathbf{E} \cdot \mathbf{J}$$

where we have used

$$\nabla \cdot (\mathbf{A} \times \mathbf{C}) = \mathbf{C} \cdot (\nabla \times \mathbf{A}) - \mathbf{A} \cdot (\nabla \times \mathbf{C})$$



Poynting's Theorem

Therefore, we have found Poynting's theorem, with $\mathbf{S} = \mathbf{E} \times \mathbf{H}$

$$-\oint_{\Sigma} (\mathbf{E} \times \mathbf{H}) \cdot d\mathbf{s} = \int_V \left(\mathbf{E} \cdot \frac{\partial \mathbf{D}}{\partial t} + \mathbf{H} \cdot \frac{\partial \mathbf{B}}{\partial t} + \mathbf{E} \cdot \mathbf{J} \right) dv$$

For a linear, isotropic, homogenous **ohmic** medium (σ_0, μ, ϵ)

$$-\oint_{\Sigma} \mathbf{S} \cdot d\mathbf{s} = \frac{d}{dt} \int_V \left(\underbrace{\frac{1}{2} \epsilon \mathbf{E}^2}_{\mathbf{W}_e} + \underbrace{\frac{1}{2} \mu \mathbf{H}^2}_{\mathbf{W}_m} \right) dv + \underbrace{\int_V \frac{1}{\sigma_0} \mathbf{J}^2 dv}_{\text{Joule heating}}$$

\mathbf{W}_e
energy density

For a sinusoidal drive:

$$\langle \mathbf{S} \rangle = \frac{1}{2} \text{Re} \{ \hat{\mathbf{E}} \times \hat{\mathbf{H}}^* \} \quad \text{and} \quad -\oint_{\Sigma} \langle \mathbf{S} \rangle \cdot d\mathbf{s} = \frac{1}{2} \int_V \frac{1}{\sigma_0} |\hat{\mathbf{J}}|^2 dv$$



Poynting's Theorem for a Superconductor

Maxwell's equations still give

$$-\oint_{\Sigma} (\mathbf{E} \times \mathbf{H}) \cdot d\mathbf{s} = \int_V \left(\mathbf{E} \cdot \frac{\partial \mathbf{D}}{\partial t} + \mathbf{H} \cdot \frac{\partial \mathbf{B}}{\partial t} + \mathbf{E} \cdot \mathbf{J} \right) dv$$

But for a superconductor

$$\mathbf{J} = \mathbf{J}_n + \mathbf{J}_s \quad \mathbf{E} = \frac{\partial}{\partial t} (\Lambda(T) \mathbf{J}_s) \quad \mathbf{E} = \frac{1}{\tilde{\sigma}_o(T)} \mathbf{J}_n$$

Therefore,

$$-\oint_{\Sigma} \mathbf{S} \cdot d\mathbf{s} = \frac{d}{dt} \int_V \left(\frac{1}{2} \epsilon \mathbf{E}^2 + \frac{1}{2} \mu_o \mathbf{H}^2 + \underbrace{\frac{1}{2} \Lambda(T) \mathbf{J}_s^2}_{W_K} \right) dv + \int_V \frac{1}{\tilde{\sigma}_o(T)} \mathbf{J}_n^2 dv$$



Kinetic Energy Density

With $\Lambda \equiv \frac{m^*}{n^*(q^*)^2}$ and $\hat{\mathbf{J}}_s = n^* q^* \hat{\mathbf{v}}$

$$w_K = \frac{1}{2} \Lambda(T) \mathbf{J}_s^2 = \underbrace{n^*(T)}_{\text{Superelectron density}} \underbrace{\left(\frac{1}{2} m^* v_s^2 \right)}_{\text{Kinetic energy of a superelectron}}$$

Energy is also stored in the kinetic energy of the superelectrons



Averaged Poynting Vector

For a sinusoidal drive:

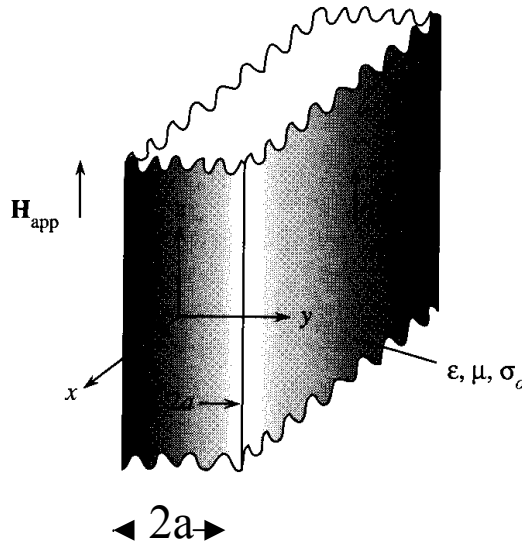
$$\langle \mathbf{S} \rangle = \frac{1}{2} \operatorname{Re} \{ \hat{\mathbf{E}} \times \hat{\mathbf{H}}^* \} \quad \text{and}$$

$$- \oint_{\Sigma} \langle \mathbf{S} \rangle \cdot d\mathbf{s} = \frac{1}{2} \int_V \frac{1}{\tilde{\sigma}_o(T)} |\hat{\mathbf{J}}_n|^2 dv$$

Energy in a superconductor is dissipated through the normal channel



Power Loss in a Slab



$$\mathbf{H} = \text{Re} \left\{ \hat{H}_o \frac{\cosh ky}{\cosh ka} e^{j\omega t} \right\} \mathbf{i}_z$$

$$k^2 = j\omega\mu_0\sigma$$

$$\frac{d}{dy} \hat{E}_x(y) = j\omega\mu \hat{H}_z(y)$$

$$\mathbf{E} = \text{Re} \left\{ \hat{H}_o \frac{k}{\sigma} \frac{\sinh ky}{\cosh ka} e^{j\omega t} \right\} \mathbf{i}_x$$

Normal Metal

$$k^2 = \frac{j}{\delta^2}$$

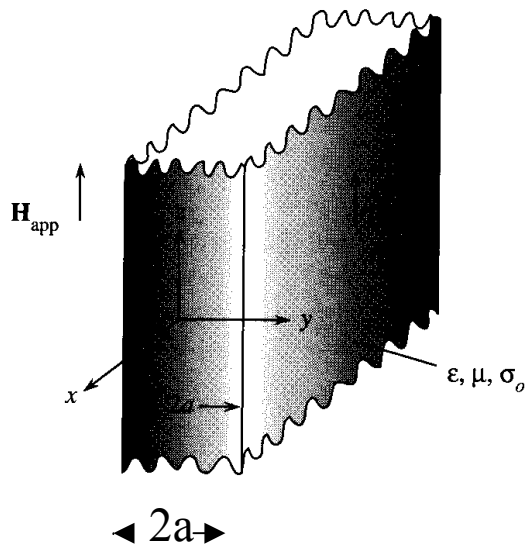
$$\sigma = \sigma_0$$

Superconductor

$$k^2 = \frac{1}{\lambda^2} \left(1 + 2j \left(\frac{\lambda}{\delta} \right)^2 \right)$$

$$\sigma = \sigma_0 + \frac{1}{j\omega\mu_0\lambda^2}$$





For a unit area, the time averaged power is

$$P_{\text{dis}} = \text{Re} \left\{ |\hat{H}_o|^2 \frac{k}{\sigma} \frac{\sinh ka}{\cosh ka} \right\}$$

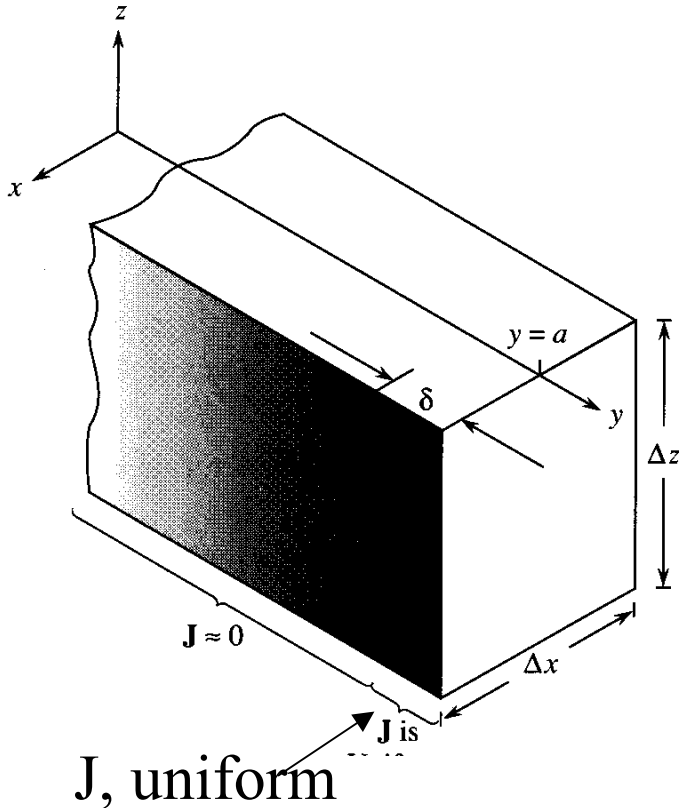
In the bulk approximation, where $\delta \ll a$,
or $\lambda \ll a$

$$P_{\text{dis}} = |\hat{H}_o|^2 \text{Re} \left\{ \frac{k}{\sigma} \right\}$$

For a normal metal:

$$P_{\text{dis}} = |\hat{H}_o|^2 \frac{1}{\delta \sigma_o} \quad \text{and surface resistance} \quad R_S = \frac{1}{\delta \sigma_o}$$

Surface Resistance: normal metal



For an area on the surface of $\Delta x \Delta z$

$$R = \frac{\Delta x}{\sigma_o \delta \Delta z}$$

The current is $|\hat{i}| = |\hat{J}_x| \delta \Delta z$

The current density is given by

$$|\hat{J}_x| = \frac{|\hat{K}_x|}{\delta} = \frac{|\hat{H}_o|}{\delta}$$

The power dissipated per unit area is

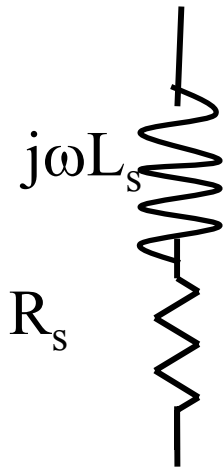
$$P_{\text{dis}} = 2 \times \frac{\frac{1}{2} |\hat{i}|^2 R}{\Delta x \Delta z} = 2 \times \frac{1}{2} |\hat{H}_o|^2 R_S = |\hat{H}_o|^2 \frac{1}{\delta \sigma_o}$$

Surface Impedance: Normal Metal

In the bulk approximation, where $\delta \ll a$, or $\lambda \ll a$, a surface impedance can be defined from

$$P_{\text{dis}} = |\hat{H}_o|^2 \operatorname{Re} \left\{ \frac{k}{\sigma} \right\} \quad \text{as} \quad Z_s = \frac{k}{\sigma}$$

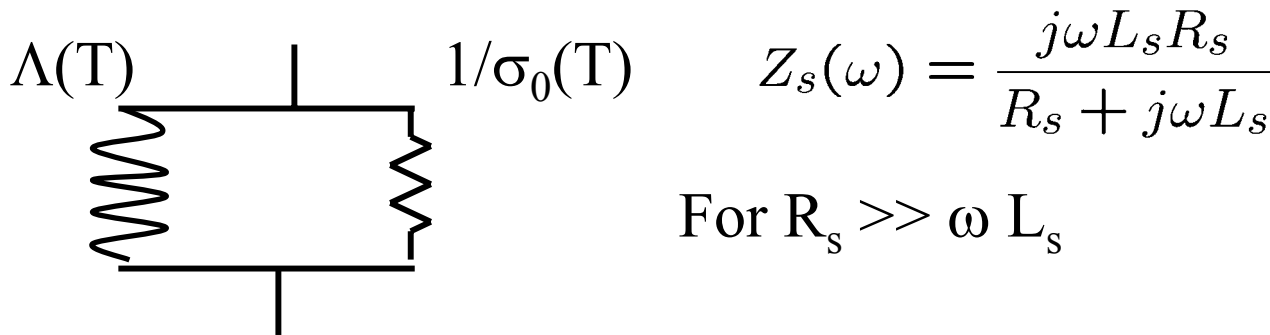
For the normal metal, $Z_S = \underbrace{\frac{1}{\delta\sigma_o}}_{R_s} + j \underbrace{\frac{1}{\delta\sigma_o}}_{L_s}$



Surface Impedance: Superconductor

For the superconductor, with $\lambda \ll \delta$, to lowest order

$$Z_S = \underbrace{\frac{2}{\delta \tilde{\sigma}_0} \left(\frac{\lambda}{\delta} \right)^3}_{R_s \sim \omega^2} + \underbrace{j\omega \mu_0 \lambda}_{L_s}$$



For $R_s \gg \omega L_s$

$$Z_s(\omega) \approx j\omega L_s (1 - j\omega L_s / R_s) = \omega^2 L_s^2 / R_s + j\omega L_s$$

For Pb at 2K and 100 MHz, $R_s = 10^{-10}$ Ohm/ \square , and Q of cavity = 10^{10}

